

YJ Planar Schottky Barrier Diode Die Specification

200V 3A, 55mil, Schottky barrier diode die based on silicon planar process

Part No.: PSB055H200SS-280A

Main Products Characteristics

- Average forward current: $I_F(AV) = 3\text{ A}$
- Maximum operating junction temperature: $T_j = 175\text{ }^{\circ}\text{C}$
- ESD rating: $>2\text{KV}$, per IEC61000-4-2 (Contact Discharge)